

MOSFET Maximum Ratings T_J = 25°C unless otherwise noted.

Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-to-Source Voltage		80	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	110	Α	
D	Pulsed Drain Current	T _C = 25°C	See Figure 4		
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	178	mJ	
D	Power Dissipation		176	W	
P _D	Derate Above 25°C		1.2	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case		0.85	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	43	°C/W	

Notes:

1: Current is limited by bondwire configuration.

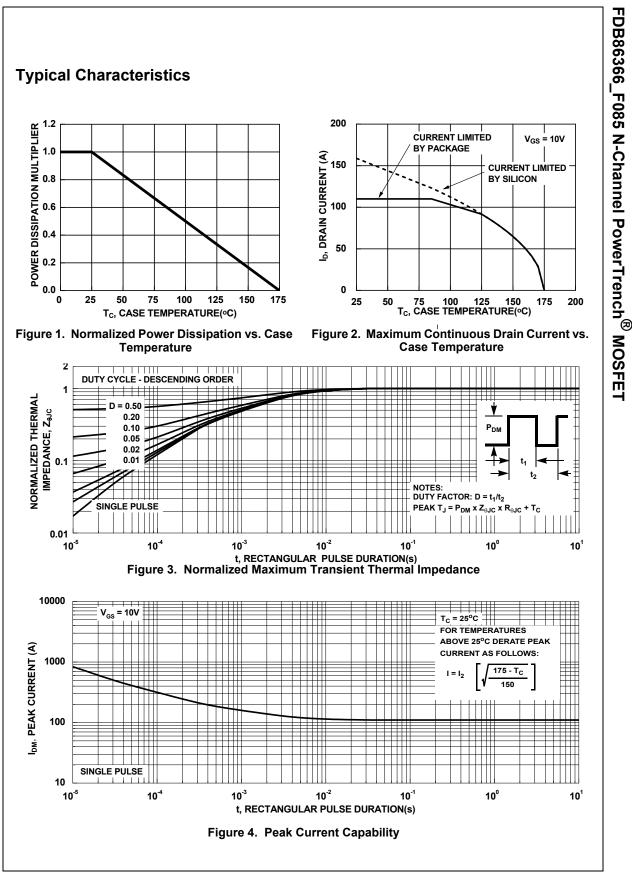
2: Starting T_J = 25°C, L = 87uH, I_{AS} = 64A, V_{DD} = 80V during inductor charging and V_{DD} = 0V during time in avalanche.

3: R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design, while R_{0JA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

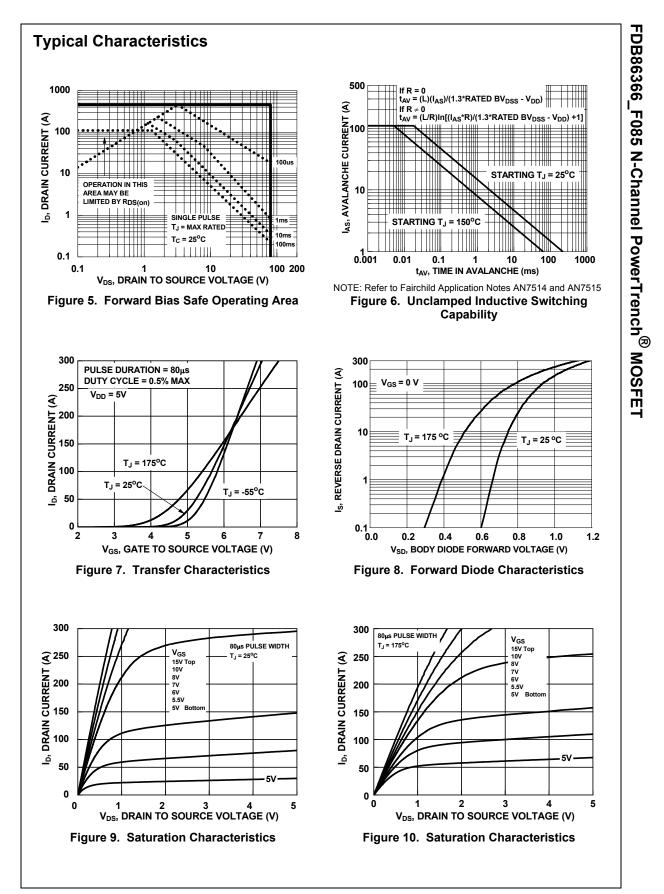
Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB86366	FDB86366_F085	D2-PAK(TO-263)	330mm	24mm	800units

Symbol	Parameter	Test Conditions		Тур.	Max.	Units
Off Cha	racteristics			1		
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V	80	-	-	V
		$V_{\rm DS}$ =80V, $T_{\rm J}$ = 25°C	-	-	1	μA
I _{DSS}	Drain-to-Source Leakage Current	$V_{GS} = 0V$ $T_J = 175^{\circ}C$ (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	V _{GS} = ±20V	-	-	±100	nA
On Cha	racteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA	2.0	3.0	4.0	V
		$I_{\rm D} = 80$ A, $T_{\rm J} = 25^{\circ}$ C	-	2.8	3.6	mΩ
R _{DS(on)}	Drain to Source On Resistance	$V_{GS} = 10V$ $T_J = 175^{\circ}C$ (Note 4)	-	5.5	7.0	mΩ
C _{iss}	Input Capacitance Output Capacitance		-	6280 1010	-	pF pF
C _{iss}		$V_{D0} = 40V$, $V_{00} = 0V$	-		-	
C _{oss}		f = 1MHz	-	32	-	pF
C _{rss}	Reverse Transfer Capacitance Gate Resistance	f = 1MHz	-	2.1	-	Ω
R _g			-	2.1 86	- 112	nC
Q _{g(ToT)}	Total Gate Charge Threshold Gate Charge	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 64V$ $V_{GS} = 0 \text{ to } 2V$ $I_D = 80A$	-	12	112	nC
Q _{g(th)}	Gate-to-Source Gate Charge	$V_{GS} = 0$ to 2V $I_D = 80A$	-	30	-	nC
Q _{gs} Q _{gd}	Gate-to-Drain "Miller" Charge		-	18	-	nC
	ng Characteristics			10		110
t _{on}	Turn-On Time		-	-	144	ns
	Turn-On Delay		-	30	-	ns
t _{d(on)} t _r	Rise Time	V _{DD} = 40V, I _D = 80A,	-	76	-	ns
t _{d(off)}	Turn-Off Delay	$V_{GS} = 10V, R_{GEN} = 6\Omega$	-	40	-	ns
t _f	Fall Time		-	17	-	ns
t _{off}	Turn-Off Time		-	-	83	ns
-	ource Diode Characteristics					
					4.05	
V _{SD}	Source-to-Drain Diode Voltage	$I_{SD} = 80A, V_{GS} = 0V$	-	-	1.25	V
		I_{SD} = 40A, V_{GS} = 0V	-	-	1.2	V
t _{rr}	Reverse-Recovery Time	$I_{F} = 80A, dI_{SD}/dt = 100A/\mu s$	-	67	87	ns
Q _{rr}	Reverse-Recovery Charge	$V_{DD} = 64V$	-	80	104	nC

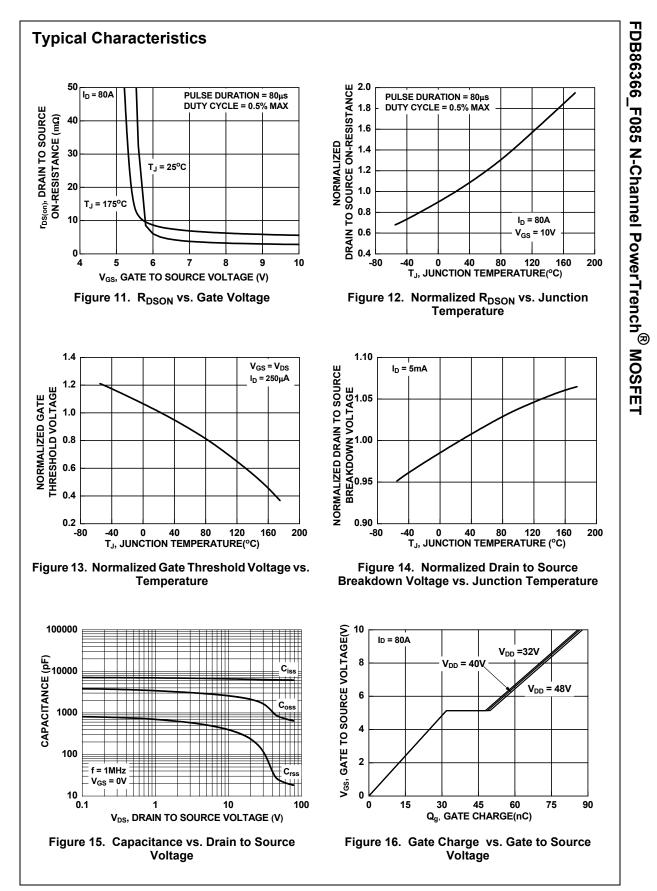


FDB86366_F085 Rev. C1



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4



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